

CY14B116N-BA25XIT

CY14B116N-BA25XIT Information

Heisener.com

Part Number CY14B116N-BA25XIT

Manufacturer Cypress Semiconductor Corp

Category Integrated Circuits (ICs)

Memory

Description NON VOLATILE SRAMS

Package -

For the pricing/inventory/lead time, please contact

us

For Reference Only

Website: https://www.heisener.com
E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









CY14B116N-BA25XIT Specifications

	Report errors?
Supplier Device Package	-
Package / Case	-
Mounting Type	-
Operating Temperature	-40°C ~ 85°C (TA)
Voltage - Supply	2.7 V ~ 3.6 V
Access Time	25ns
Write Cycle Time - Word, Page	25ns
Clock Frequency	-
Memory Interface	Parallel
Memory Size	16Mb (1M x 16)
Technology	NVSRAM (Non-Volatile SRAM)
Memory Format	NVSRAM
Memory Type	Non-Volatile
Series	-
Package	-
	Memory
Category	Integrated Circuits (ICs)
Manufacturer	Cypress Semiconductor Corp
Manufacturer Part Number	CY14B116N-BA25XIT

CY14B116N-BA25XIT Guarantees



Ouality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

CY14B116N-BA25XIT Payment Methods



















CY14B116N-BA25XIT Shipping Methods













If you have any question about CY14B116N-BA25XIT, please do not hesitate to contact us!

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